

General Purpose Transistors

NPN Silicon

Pb– Free Package May be Available. The G.Suffix Denotes a
Pb– Free Lead Finish

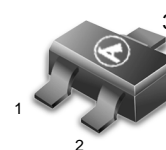
ORDERING INFORMATION (Pb– Free)

Device	Package	Shipping
LBC846AWT1G,BWT1G	SOT-323	3000/Tape & Reel
LBC847AWT1G,BWT1G,CWT1G	SOT-323	3000/Tape & Reel
LBC848AWT1G,BWT1G,CWT1G	SOT-323	3000/Tape & Reel

MAXIMUM RATINGS

Rating	Symbol	BC846	BC847	BC848	Unit
Collector–Emitter Voltage	V_{CE0}	65	45	30	V
Collector–Base Voltage	V_{CBO}	80	50	30	V
Emitter–Base Voltage	V_{EBO}	6.0	6.0	5.0	V
Collector Current — Continuous	I_C	100	100	100	mAdc

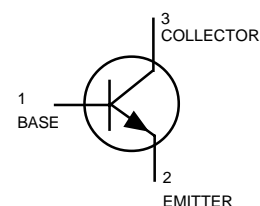
LBC846AWT1,BWT1
LBC847AWT1,BWT1
CWT1
LBC848AWT1,BWT1
CWT1



SOT–323 /SC–70

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	150	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Total Device Dissipation	P_D	2.4	mW/ $^\circ\text{C}$
Junction and Storage Temperature	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$



DEVICE MARKING

LBC846AWT1 = 1A; LBC846BWT1 = 1B; LBC847AWT1 = 1E; LBC847BWT1 = 1F;
LBC847CWT1 = 1G; LBC848AWT1 = 1J; LBC848BWT1 = 1K; LBC848CWT1 = 1L

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ($I_C = 10\text{ mA}$)	LBC846 Series	65	—	—	v
	LBC847 Series	45	—	—	
	LBC848 Series	30	—	—	
Collector–Emitter Breakdown Voltage ($I_C = 10\ \mu\text{A}, V_{EB} = 0$)	LBC846 Series	80	—	—	v
	LBC847 Series	50	—	—	
	LBC848 Series	30	—	—	
Collector–Base Breakdown Voltage ($I_C = 10\ \mu\text{A}$)	LBC846 Series	80	—	—	v
	LBC847 Series	50	—	—	
	LBC848 Series	30	—	—	
Emitter–Base Breakdown Voltage ($I_E = 1.0\ \mu\text{A}$)	LBC846 Series	6.0	—	—	v
	LBC847 Series	6.0	—	—	
	LBC848 Series	5.0	—	—	
Collector Cutoff Current ($V_{CB} = 30\text{ V}$) ($V_{CB} = 30\text{ V}, T_A = 150^\circ\text{C}$)	I_{CBO}	—	—	15	nA
		—	—	5.0	μA

1.FR–5=1.0 x 0.75 x 0.062in

LBC846AWT1,BWT1 LBC847AWT1,BWT1 CWT1 LBC848AWT1,BWT1,CWT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_C = 10 \mu\text{A}$, $V_{CE} = 5.0 \text{ V}$)	h_{FE}	—	90	—	—
		—	150	—	—
		—	270	—	—
($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$)		110	180	220	
		200	290	450	
		420	520	800	
Collector–Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$)	$V_{CE(sat)}$	—	—	0.25 0.6	V
Base–Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$)	$V_{BE(sat)}$	—	0.7 0.9	—	V
Base–Emitter Voltage ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$)	$V_{BE(on)}$	580	660	700 770	mV

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 100 \text{ MHz}$)	f_T	100	—	—	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}$, $f = 1.0 \text{ MHz}$)	C_{obo}	—	—	4.5	pF
Noise Figure ($I_C = 0.2 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $R_S = 2.0 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$, $BW = 200 \text{ Hz}$)	NF	—	—	10 4.0	dB

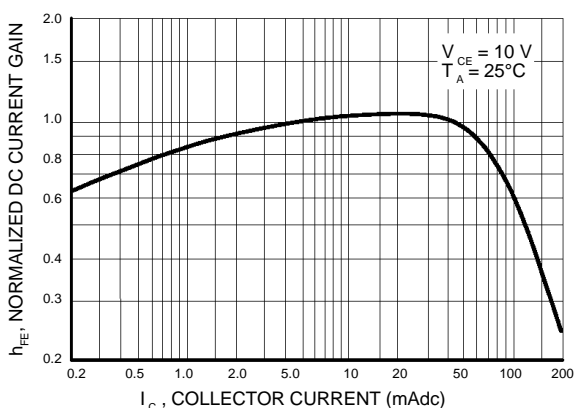


Figure 1. Normalized DC Current Gain

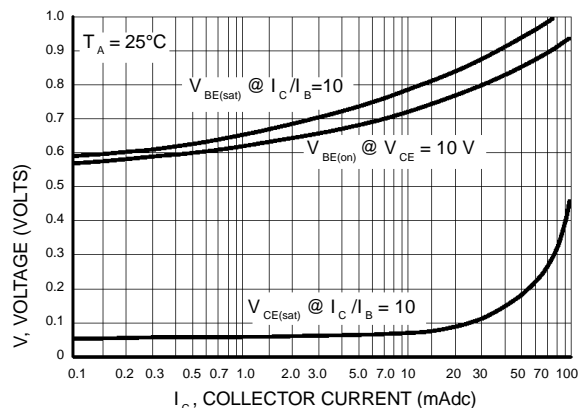


Figure 2. "Saturation" and "On" Voltages

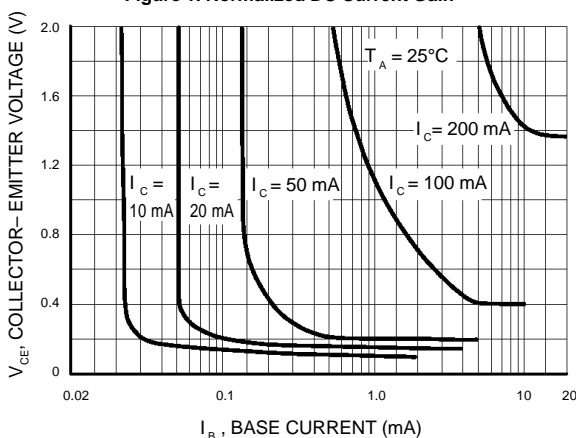


Figure 3. Collector Saturation Region

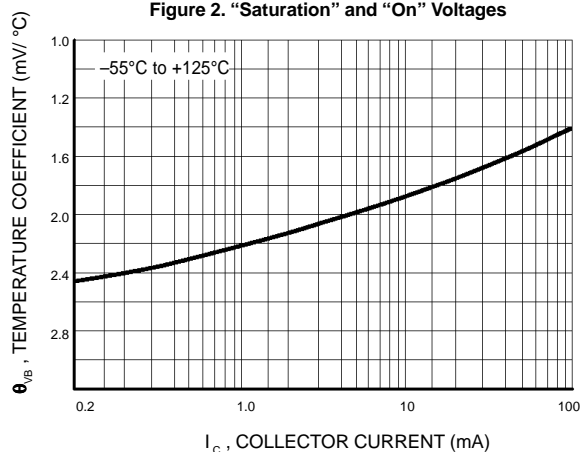


Figure 4. Base–Emitter Temperature Coefficient

LBC846AWT1, BWT1 LBC847AWT1, BWT1, CWT1 LBC848AWT1, BWT1, CWT1

LBC847/LBC848

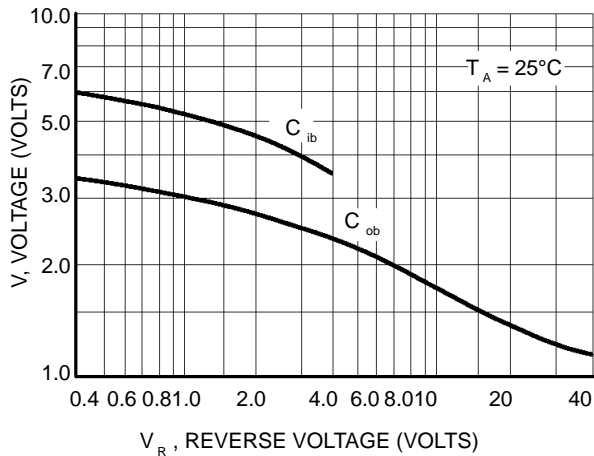


Figure 5. Capacitances

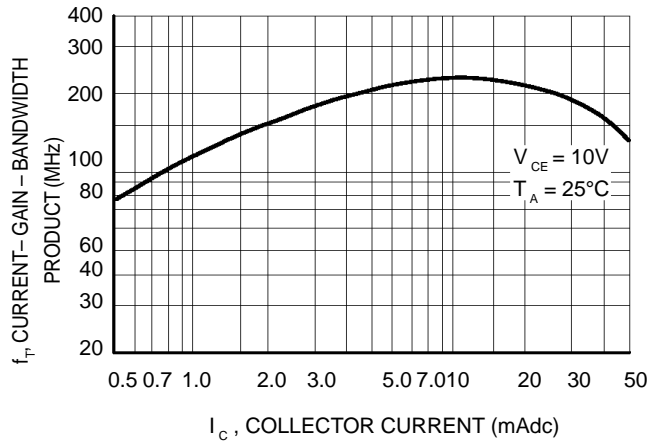


Figure 6. Current-Gain - Bandwidth Product

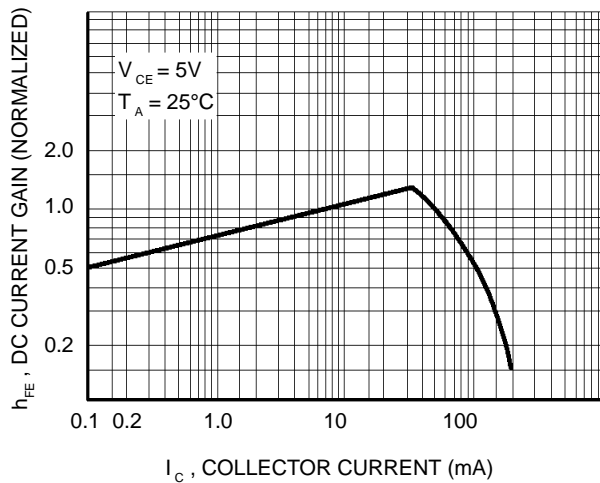


Figure 7. DC Current Gain

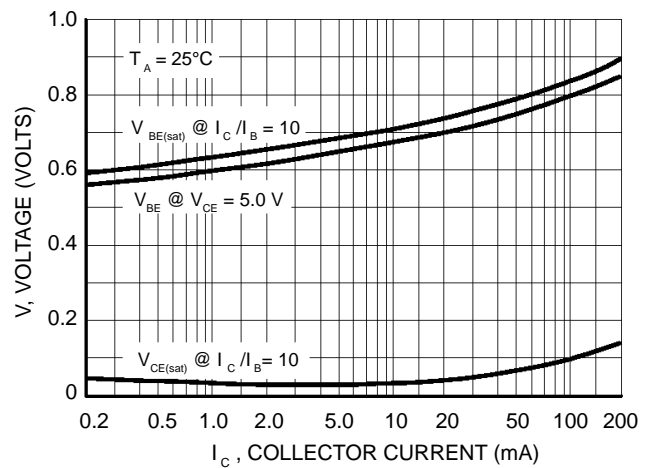


Figure 8. "On" Voltage

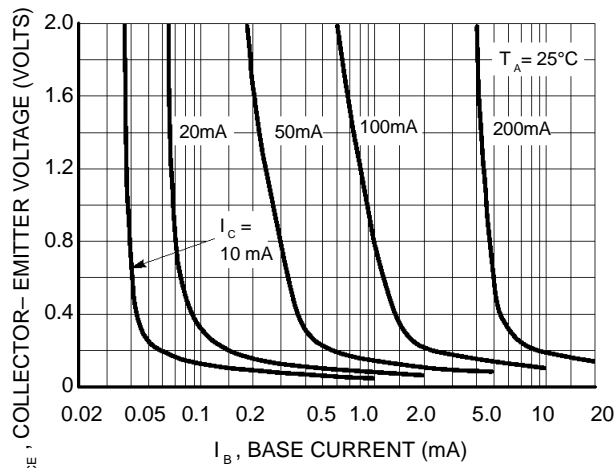


Figure 9. Collector Saturation Region

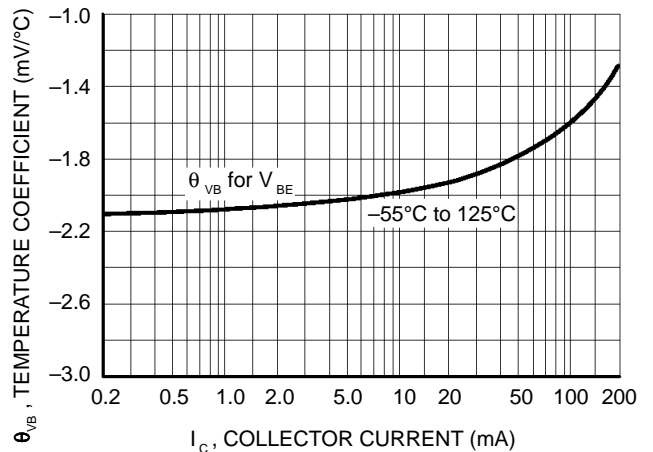


Figure 10. Base-Emitter Temperature Coefficient

LBC846AWT1, BWT1 LBC847AWT1, BWT1, CWT1 LBC848AWT1, BWT1, CWT1

LBC846

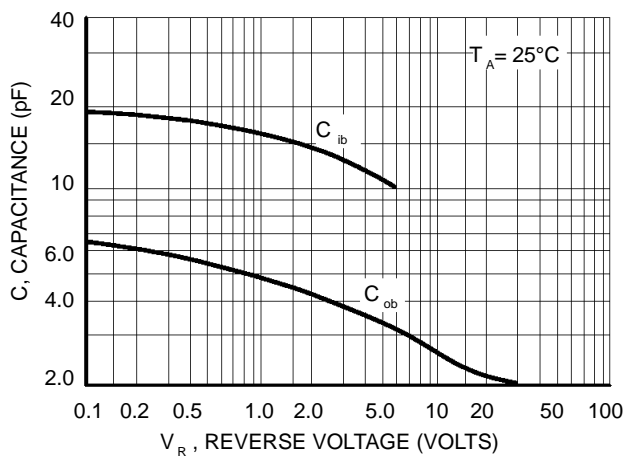


Figure 11. Capacitance

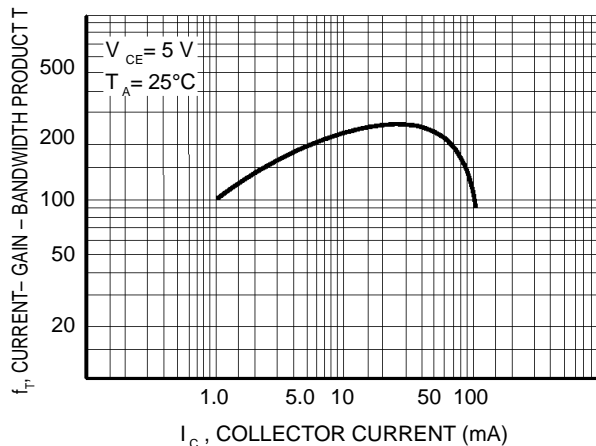
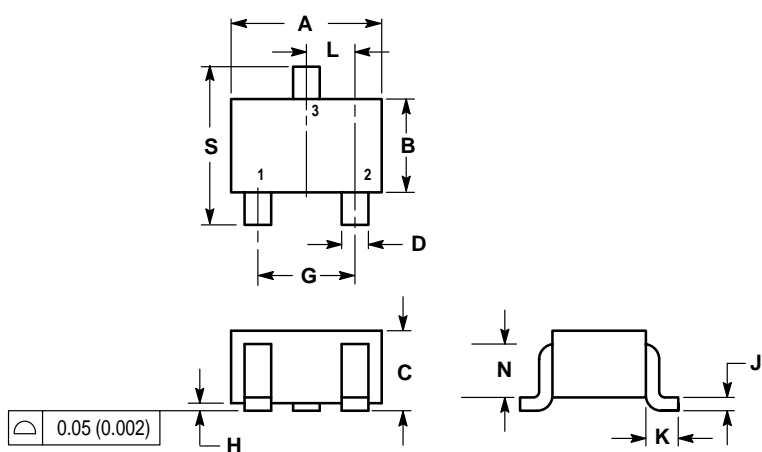


Figure 12. Current-Gain - Bandwidth Product

SC-70 / SOT-323

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

- PIN 1. BASE
2. EMITTER
3. COLLECTOR

